

SiC Schottky Barrier Diode

| V_R | 650V |
|----------------|------|
| I _F | 4A |
| Q_{C} | 11nC |

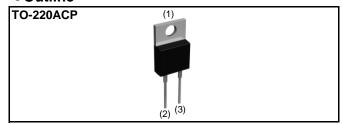
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

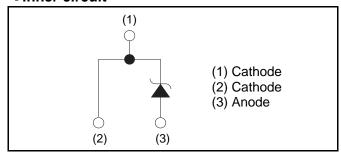
Construction

Silicon carbide epitaxial planar type

Outline



•Inner circuit



Packaging specifications

| | ging opcomoditions | |
|------|---------------------------|----------|
| | Packaging | Tube |
| | Reel size (mm) | - |
| Typo | Tape width (mm) | - |
| Туре | Basic ordering unit (pcs) | 50 |
| | Packing code | C9 |
| | Marking | SCS304AP |

•Absolute maximum ratings $(T_i = 25^{\circ}C)$

| Parameter | | Symbol | Value | Unit |
|---------------------------------|---|------------------|-------------|------------------|
| Reverse voltage (re | epetitive peak) | V_{RM} | 650 | V |
| Reverse voltage (D | C) | V_{R} | 650 | V |
| Continuous forward | current (T _c = 140°C) | I _F | 4 | А |
| Surge non- | PW=10ms sinusoidal, T _j =25°C | | 27 | А |
| repetitive forward | PW=10ms sinusoidal, T _j =150°C | I _{FSM} | 22 | А |
| current | PW=10μs square, T _j =25°C | • | 100 | А |
| Repetitive peak forward current | | I _{FRM} | 20 *1 | А |
| 1≦PW≦10ms, T _j =25°C | | $\int i^2 dt$ | 3.6 | A ² s |
| i ² t value | 1≦PW≦10ms, T _j =150°C | J rat | 2.4 | A ² s |
| Total power disspation | | P_{D} | 34 *2 | W |
| Junction temperature | | T _j | 175 | °C |
| Range of storage temperature | | T _{stg} | -55 to +175 | °C |

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

| Parameter | Symbol | Conditions | Values | | | Linit |
|------------------------------------|------------------|--|--------|-------|------|-------|
| | | | Min. | Тур. | Max. | Unit |
| DC blocking voltage | V_{DC} | I _R =20μA | 650 | - | - | V |
| | | I _F =4A,T _j =25°C | - | 1.35 | 1.50 | V |
| Forward voltage | | I _F =4A,T _j =150°C | - | 1.44 | 1.71 | V |
| | | I _F =4A,T _j =175°C | - | 1.50 | - | V |
| Reverse current | I _R | V _R =650V,T _j =25°C | - | 0.012 | 20 | μΑ |
| | | V _R =650V,T _j =150°C | - | 0.8 | 80 | μΑ |
| | | V _R =650V,T _j =175°C | - | 2.4 | - | μΑ |
| Total capacitance | С | V _R =1V,f=1MHz | - | 200 | - | pF |
| | | V _R =650V,f=1MHz | - | 18 | - | pF |
| Total capacitive charge | Q_{C} | V _R =400V,di/dt=350A/μs | - | 11 | - | nC |
| Switching time | t _C | V _R =400V,di/dt=350A/μs | - | 14 | - | ns |
| Non-repetetive Avaranche Energy | E _{ava} | L=1mH | - | 48 | 1 | mJ |

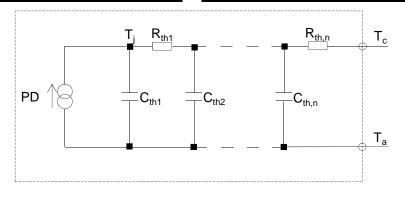
●Thermal characteristics

| Parameter | Symbol | Conditions | Values | | | Unit |
|--------------------|----------------------|------------|--------|------|------|-------|
| | | | Min. | Тур. | Max. | Offic |
| Thermal resistance | R _{th(j-c)} | - | - | 3.0 | 4.4 | °C/W |

● Typical Transient Thermal Characteristics

| Symbol | Value | Unit |
|------------------|----------|------|
| R _{th1} | 3.91E-02 | |
| R _{th2} | 3.76E-01 | K/W |
| R _{th3} | 2.54E+00 | |

| Symbol | Value | Unit |
|------------------|----------|------|
| C _{th1} | 1.01E-04 | |
| C _{th2} | 4.02E-04 | Ws/K |
| C _{th3} | 1.19E-03 | |



• Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

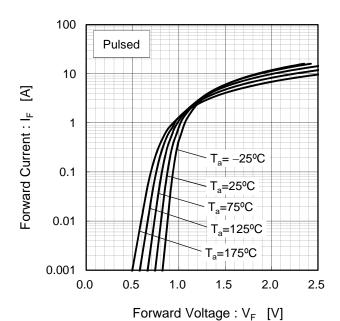
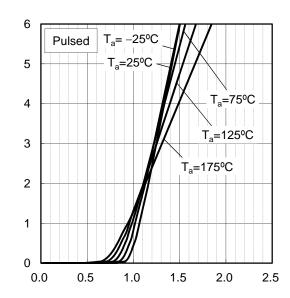


Fig.2 V_F - I_F Characteristics

Forward Current : IF [A]



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

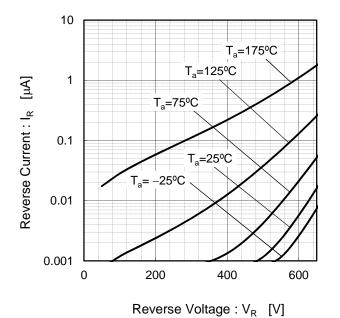
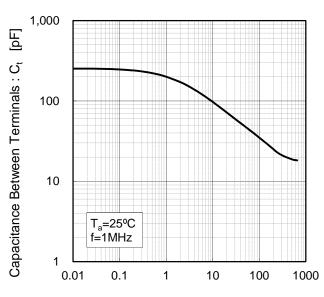


Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

• Electrical characteristic curves

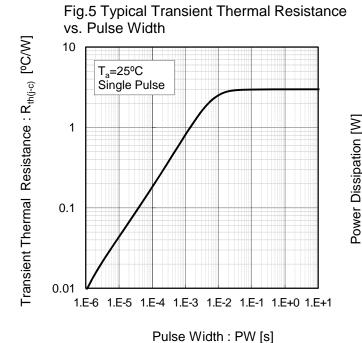
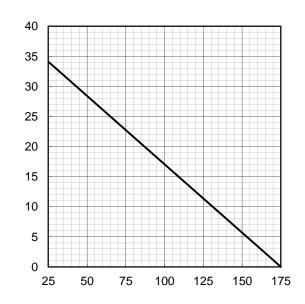


Fig.6 Power Dissipation



Case Temperature : T_c [°C]

Fig.7*3 Maximum peak forward current derating curve $I_P - T_c$

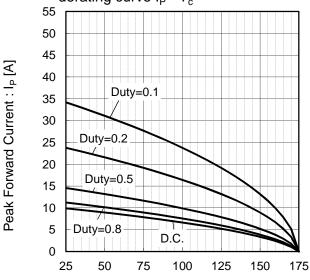
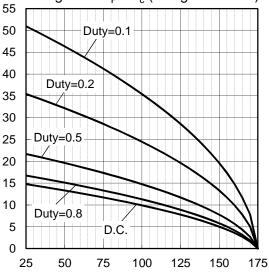


Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



Case Temperature : T_c [°C]

*4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

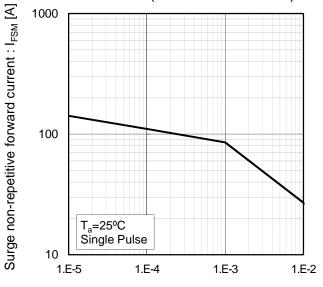
Case Temperature : T_c [°C] 3 Based on max Vf, max $R_{th(i-c)}$

*3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

Peak Forward Current: Ip [A]

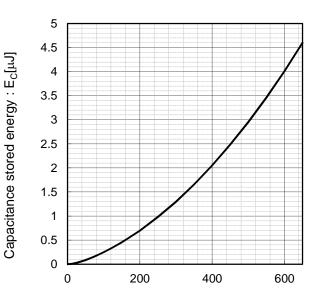
• Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

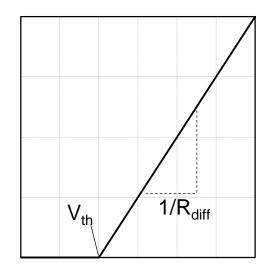
Fig.10 Typical capacitance store energy



Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

| Symbol | Typical Value | Unit |
|----------------|---------------|------------------------|
| a_0 | 9.66E-01 | V |
| a ₁ | -1.10E-0.3 | V/°C |
| b ₀ | 8.80E-02 | Ω |
| b ₁ | 1.87E-04 | Ω/°C |
| b ₂ | 1.92E-06 | $\Omega/^{\circ}C^{2}$ |

 T_i in °C; -55 °C < T_i <175 °C ; I_F <8 A

Forward Current: IF

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